

CMOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

High-Voltage Types (20-Volt Rating)

■ CD4060B consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-0's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of ϕI (and ϕO). All inputs and outputs are fully buffered. Schmitt trigger action on the input-pulse line permits unlimited input-pulse rise and fall times.

The CD4060B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline package (NSR suffix), and in chip form (H suffix).

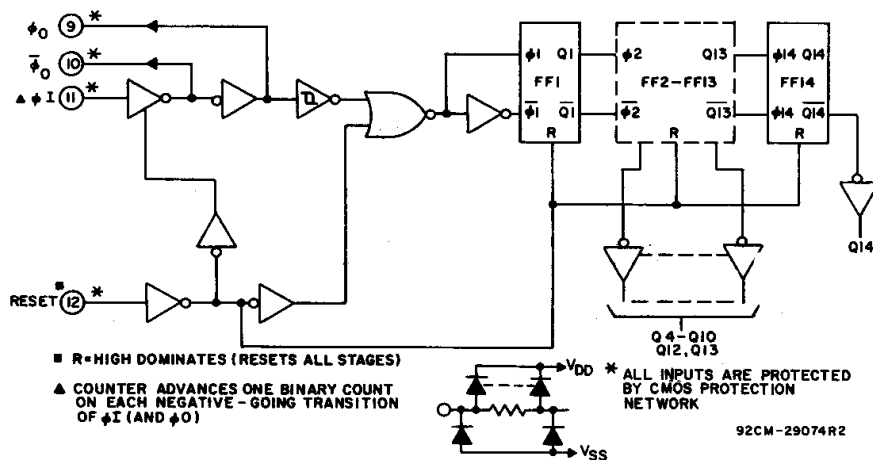


Fig. 1 – Logic diagram.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal) -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS

..... -0.5V to $V_{DD} + 0.5V$

DC INPUT CURRENT, ANY ONE INPUT

..... $\pm 10mA$

POWER DISSIPATION PER PACKAGE (P_D):

For $T_A = -55^\circ C$ to $+100^\circ C$ 500mW

For $T_A = +100^\circ C$ to $+125^\circ C$ Derate Linearly at 12mW/ $^\circ C$ to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW

OPERATING-TEMPERATURE RANGE (T_A)

..... $-55^\circ C$ to $+125^\circ C$

STORAGE TEMPERATURE RANGE (T_{stg})

..... $-65^\circ C$ to $+150^\circ C$

LEAD TEMPERATURE (DURING SOLDERING):

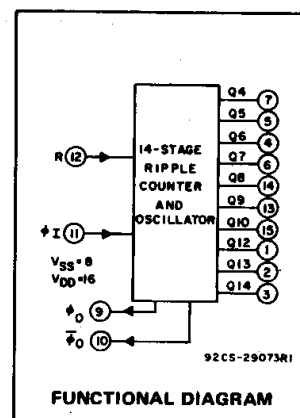
At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79mm$) from case for 10s max $+265^\circ C$

Features:

- 12 MHz clock rate at 15 V
- Common reset
- Fully static operation
- Buffered inputs and outputs
- Schmitt trigger input-pulse line
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for description of "B" Series CMOS Devices"

Oscillator Features:

- All active components on chip
- RC or crystal oscillator configuration
- RC oscillator frequency of 690 kHz min. at 15 V



Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

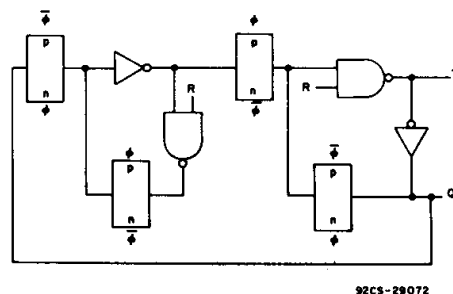


Fig. 2 – Detail of typical flip-flop stage.

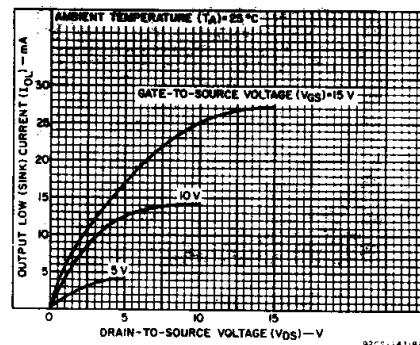


Fig. 3 – Typical n-channel output low (sink) current characteristics.

CD4060B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0,5	5	5	5	150	150	—	0.04	5	μA
	—	0,10	10	10	10	300	300	—	0.04	10	
	—	0,15	15	20	20	600	600	—	0.04	20	
	—	0,20	20	100	100	3000	3000	—	0.08	100	
Output Low (Sink) Current*, I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current*, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage V _{IL} Max.	0.5,4.5	—	5	1.5				—	—	1.5	V
	1,9	—	10	3				—	—	3	
	1.5,13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5,4.5	—	5	3.5				3.5	—	—	V
	1,9	—	10	7				7	—	—	
	1.5,13.5	—	15	11				11	—	—	
Input Current I _{IN} Max.	—	0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA

* Data not applicable to terminal 9 or 10.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

CHARACTERISTIC	V_{DD}	LIMITS		UNITS
		MIN.	MAX.	
Supply-Voltage Range (For T_A = Full Package Temperature Range)	—	3	18	V
Input-Pulse Width, t_W ($f = 100$ kHz)	5	100	—	ns
	10	40	—	
	15	30	—	
Input-Pulse Rise Time and Fall Time, $t_{r\phi}$, $t_{f\phi}$	5	Unlimited		
	10			
	15			
Input-Pulse Frequency, $f_{\phi I}$ (External pulse source)	5	—	3.5	MHz
	10	—	8	
	15	—	12	
Reset Pulse Width, t_W	5	120	—	ns
	10	60	—	
	15	40	—	

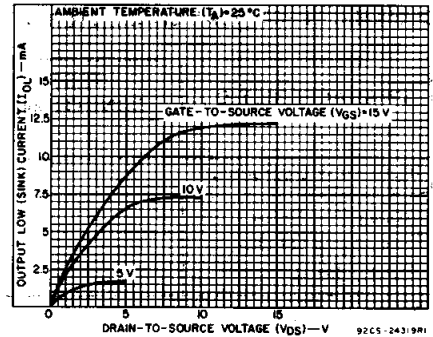


Fig. 4 — Minimum n-channel output low (sink) current characteristics.

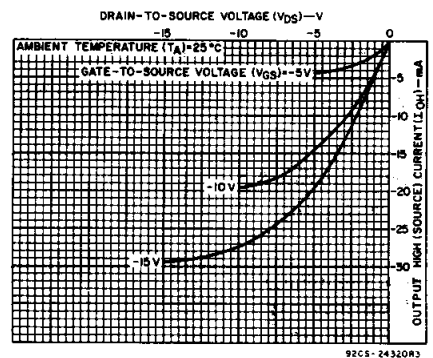


Fig. 5 — Typical p-channel output high (source) current characteristics.

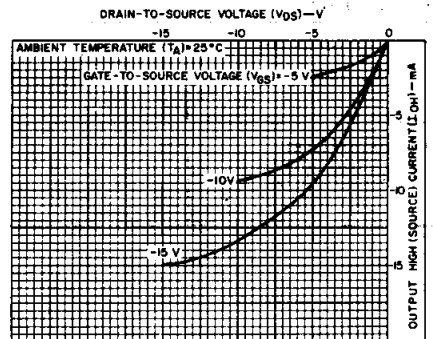


Fig. 6 — Minimum p-channel output high (source) current characteristics.

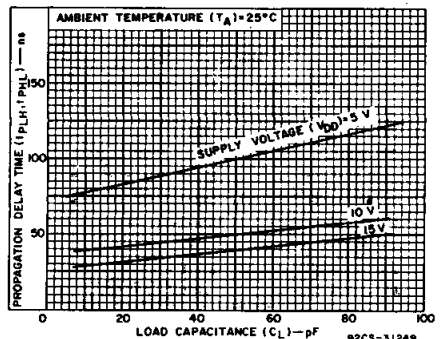


Fig. 7 — Typical propagation delay time (Q_n to Q_{n+1}) as a function of load capacitance.

CD4060B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Input $t_r, t_f = 20\text{ ns}$,
 $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	TEST CONDITIONS	LIMITS				UNITS
		V _{DD} (V)	MIN.	TYP.	MAX.	
Input-Pulse Operation						
Propagation Delay Time, ϕ_I to Q4 Out; t_{PHL} , t_{PLH}		5	—	370	740	ns
		10	—	150	300	
		15	—	100	200	
Propagation Delay Time, Q_n to Q_{n+1} ; t_{PHL} , t_{PLH}		5	—	100	200	
		10	—	50	100	
		15	—	40	80	
Transition Time, t_{THL} , t_{TLH}		5	—	100	200	
		10	—	50	100	
		15	—	40	80	
Min. Input-Pulse Width, t_W	f = 100 kHz	5	—	50	100	
		10	—	20	40	
		15	—	15	30	
Input-Pulse Rise & Fall Time, $t_{r\phi}$, $t_{f\phi}$		5	Unlimited			
		10				
		15				
Max. Input-Pulse Frequency, $f_{\phi I}$ (External pulse source)		5	3.5	7	—	MHz
		10	8	16	—	
		15	12	24	—	
Input Capacitance, C_1	Any Input		—	5	7.5	pF
Reset Operation						
Propagation Delay Time, t_{PHL}		5	—	180	360	ns
		10	—	80	160	
		15	—	50	100	
Minimum Reset Pulse Width, t_W		5	—	60	120	
		10	—	30	60	
		15	—	20	40	

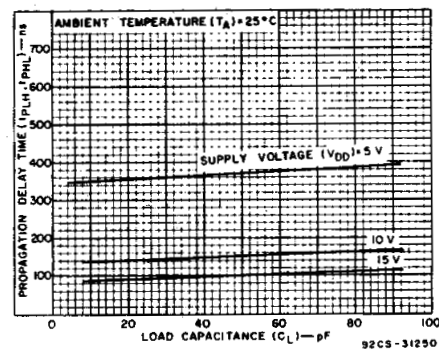


Fig. 8 - Typical propagation delay time (ϕ_I to Q_4 Output) as a function of load capacitance.

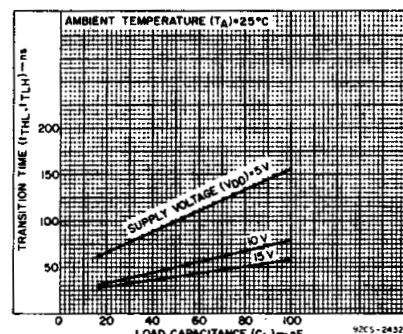


Fig. 9 - Typical transition time as a function of load capacitance.

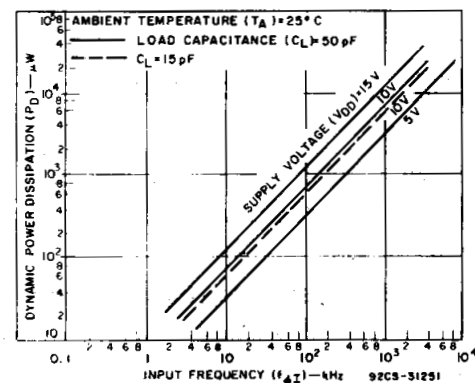


Fig. 10 - Typical dynamic power dissipation as a function of input frequency.

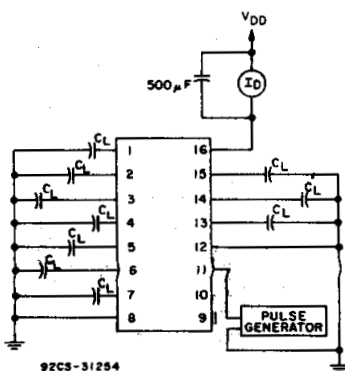


Fig. 11 - Dynamic power dissipation test circuit.

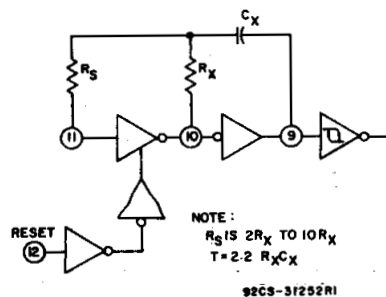


Fig. 12 - Typical RC circuit.

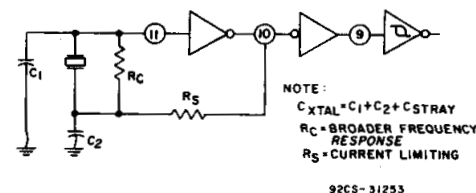


Fig. 13 - Typical crystal circuit.

CD4060B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Input $t_r, t_f = 20\text{ ns}$,
 $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$ [cont'd]

CHARACTERISTIC	TEST CONDITIONS	LIMITS				UNITS
		V _{DD} (V)	Min.	Typ.	Max.	
RC Operation						
Variation of Fre- quency (Unit-to-Unit)	C _X = 200 pF, R _S = 560 kΩ, R _X = 50 kΩ	5	—	23±10%	—	kHz
		10	—	24±10%	—	
		15	—	25±10%	—	
Variation of Fre- quency with voltage change (Same Unit)	C _X = 200 pF, R _S = 560 kΩ, R _X = 50 kΩ	5V to 10 V 10V to 15V	— —	1.5 0.5	— —	
R _X max.	C _X = 10 μF = 50 μF = 10 μF	5	—	—	20	MΩ
		10	—	—	20	
		15	—	—	10	
C _X max.	R _X = 500 kΩ = 300 kΩ = 300 kΩ	5	—	—	1000	μF
		10	—	—	50	
		15	—	—	50	
Maximum Oscillator Frequency*	R _X = 5 kΩ R _S = 30 kΩ C _X = 15 pF	10	530	650	810	kHz
		15	690	800	940	
Drive Current at Pin 9 (For Oscillator Design)	I _{OL}	V _O = 0.4 V	5	0.16	0.35	mA
		= 0.5 V	10	0.42	0.8	
		= 1.5 V	15	1	2	
	I _{OH}	V _O = 4.6 V	5	-0.16	-0.35	
		= 9.5 V	10	-0.42	-0.8	
		= 13.5 V	15	-1	-2	

*RC oscillator applications are not recommended at supply voltages below 7 V for $R_X < 50\text{ k}\Omega$.

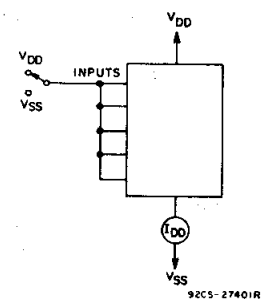


Fig. 14 — Quiescent device current.

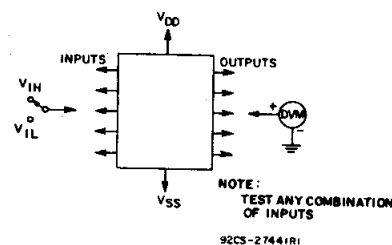


Fig. 15 — Input voltage.

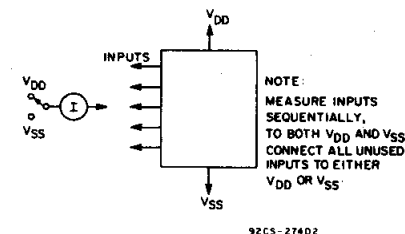
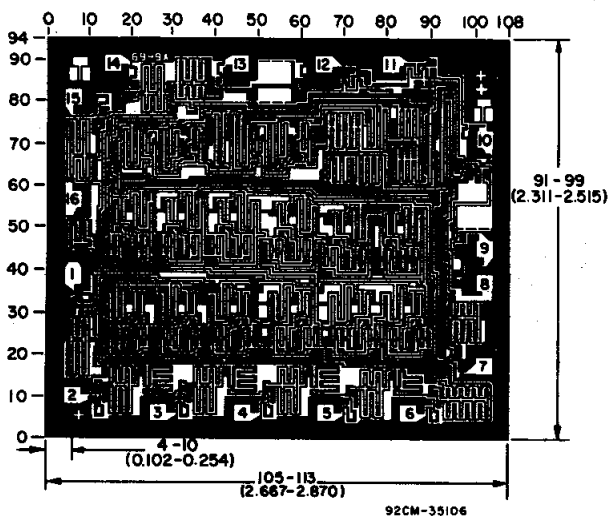
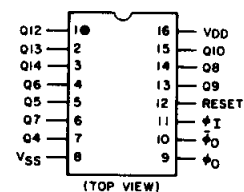


Fig. 16 — Input current.



Chip dimensions and pad layout for CD4060B

TERMINAL DIAGRAM



92CS-2376IR2

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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